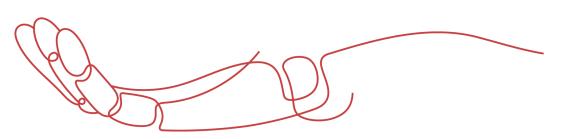




# **PRODUCT DATA SHEET**



To learn more about JGSEMI, please visit our website at







Datasheet

urces Samples

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO\_questions@jgsemi.com.



# **PSUR1610DNV07**

Transient Voltage Suppressor

#### **Feature**

- 1400W Peak pulse power per line (t<sub>P</sub> = 8/20µs)
- DFN1610-2L package
- Response time is typically < 1 ns
- Protect one I/O or power line
- Low clamping Voltage
- · RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)



## **Circuit Diagram**

### **Applications**

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- · Notebooks, desktops, and servers
- Portable instrumentation
- · Cordless phones
- · Digital cameras
- Peripherals
- MP3 players

### **Mechanical Characteristics**

• Lead finish:100% matte Sn(Tin)

Mounting position: Any

Qualified max reflow temperature:260°C

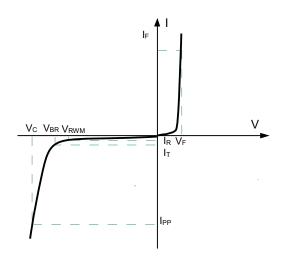
Pure tin plating: 7 ~ 17 um

• Pin flatness:≤3mil

· Device meets MSL3 requirements

#### **Electronics Parameter**

Symbol	Parameter	
V <sub>RWM</sub>	Peak Reverse Working Voltage	
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>	
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>	
lτ	Test Current	
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
P <sub>PP</sub>	Peak Pulse Power	
CJ	Junction Capacitance	
lF	Forward Current	
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>	





# Electrical characteristics per line@25 ℂ ( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	$V_{RWM}$				7	٧
Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> =1mA		8	9.5	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =7V			1	μA
Clamping Voltage	Vc	$I_{PP}$ =70A $t_P$ = 8/20 $\mu$ s		20	24	V
Junction Capacitance	Cj	V <sub>R</sub> =0V f = 1MHz	650	700	750	pF

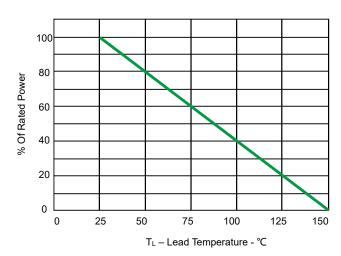
# Absolute maximum rating@25°C

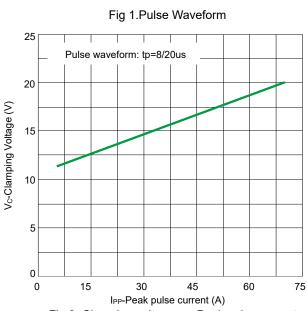
Rating	Symbol	Value	Units
Peak Pulse Power ( t₂ = 8/20μS )	P <sub>pp</sub>	1400	W
Lead Soldering Temperature	T∟	260 (10 sec)	℃
Operating Temperature	TJ	-55 to +125	℃
Storage Temperature	T <sub>STG</sub>	-55 to +150	℃



# **Typical Characteristics**







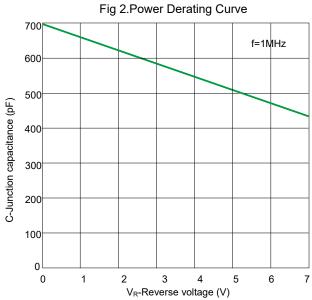
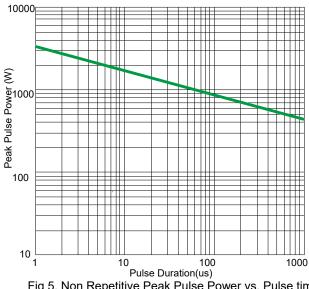
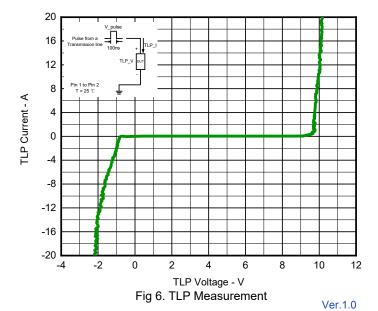


Fig 3. Clamping voltage vs. Peak pulse current

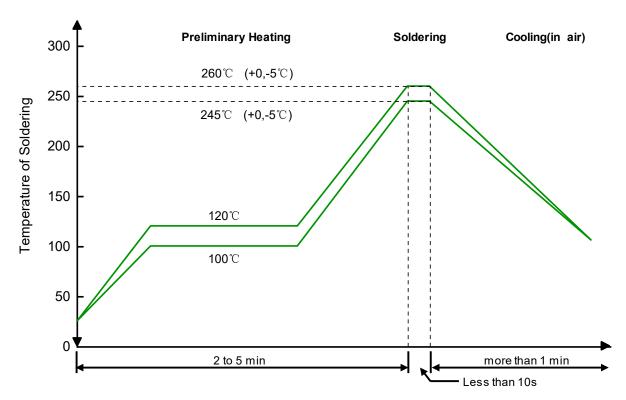
Fig 4. Capacitance vs. Reveres voltage







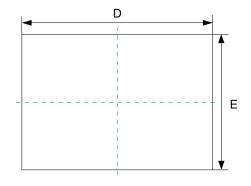
### **Solder Reflow Recommendation**

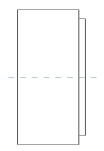


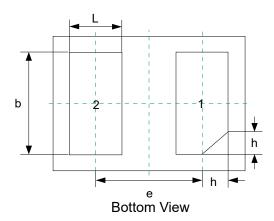
Remark: Pb free for 260°C; Pb for 245°C.

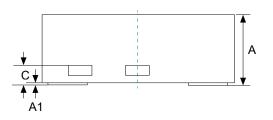


# **Product dimension (DFN1610-2L)**

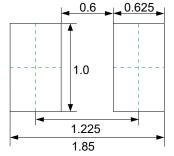








Dim	Millimeters			
	MIN	MAX		
Α	0.40	0.60		
A1		0.05		
b	0.75	0.85		
С	0.10	0.20		
D	1.55	1.65		
е	1.10BSC			
E	0.95	1.05		
L	0.35	0.45		
h	0.15	0.25		



Recommended Soldering Pad

Unit:mm



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